

## Precision Voltage Reference

### FEATURES

- Initial Voltage Tolerance ..... 1004-1.2,  $\pm 4\text{mV}$  & 1004-2.5,  $\pm 20\text{mV}$
- Low Dynamic Impedance .....  $0.6\ \Omega$  Max.
- Low Operating Current ..... 1004-1.2,  $10\mu\text{A}$  & 1004-2.5,  $20\mu\text{A}$
- Wide Operating Current Range .....  $10\mu\text{A}$  to  $20\text{mA}$
- Direct Replacement for LT1004 & LM1004

### APPLICATIONS

- A/D and D/A Reference
- Reference for 5V Systems
- Digital Voltmeter
- Power Supply Monitor

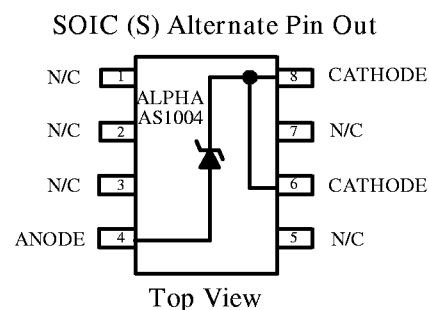
### PRODUCT DESCRIPTION

The ALPHA Semiconductor AS1004 is a 2-terminal band-gap precision voltage reference which provides a stable fixed output voltage of 1.2 and 2.5 volts with a tolerance less than  $\pm 4\text{mV}$  for AS1004-1.2 and  $\pm 10\text{mV}$  for AS1004-2.5. ALPHA Semiconductor's design, process, and precise on chip trimming enable us to achieve low temperature coefficient as low as  $25\text{ppm}/^\circ\text{C}$ .

The AS1004 can be used as a pin-to-pin replacement of the LT1004 and LM1004. The AS1004 is available in packages SOIC-8, SOT-89, TO-92 and Die at the operating temperature range of  $0^\circ\text{C}$  to  $70^\circ\text{C}$ .

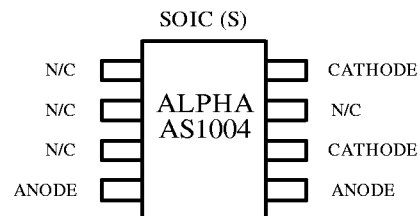
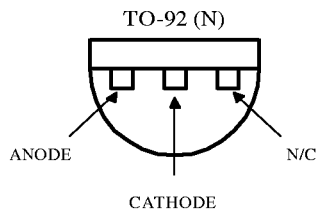
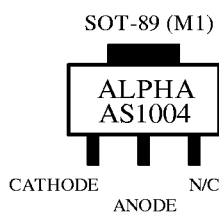
### ORDERING INFORMATION

| Part Number | MAX<br>TEMPCO <sup>1</sup><br>ppm/ $^\circ\text{C}$ | Package<br>Type | Oper. Temp.<br>Range |
|-------------|-----------------------------------------------------|-----------------|----------------------|
| AS1004M1    | 25                                                  | SOT-89          | COM                  |
| AS1004S     | 25                                                  | SO-8            | COM                  |
| AS1004N     | 25                                                  | TO-92           | COM                  |



### PIN CONNECTIONS

#### TOP VIEW



## ABSOLUTE MAXIMUM RATINGS

|                                       |                |
|---------------------------------------|----------------|
| Forward Current.....                  | 30 mA          |
| Reverse Current.....                  | 30 mA          |
| Maximum Junction Temp.....            | 150°C          |
| Storage Temperature Range.....        | -65°C to 150°C |
| Lead Temperature Range (10 Sec.)..... | +300°C         |

## TYPICAL THERMAL RESISTANCES

| Package | $\theta_{JA}$ | $\theta_{JC}$ | Typical Derating |
|---------|---------------|---------------|------------------|
| TO-92   | 160 °C/W      | 80 °C/W       | 6.3 mW/°C        |
| 8L SOIC | 175 °C/W      | 45 °C/W       | 5.7 mW/°C        |
| SOT-89  | 110 °C/W      | 8 °C/W        | 9.1 mW/°C        |

**ELECTRICAL CHARACTERISTICS** Electrical Characteristics are guaranteed over full junction temperature range (0°C to 70°C). Ambient temperature must be derated based on power dissipation and package thermal characteristics.

| Parameter                                     | Test Conditions                            | AS1004-1.2V |       |       | AS1004-2.5V |       |       | Units    |
|-----------------------------------------------|--------------------------------------------|-------------|-------|-------|-------------|-------|-------|----------|
|                                               |                                            | Min.        | Typ.  | Max.  | Min.        | Typ.  | Max.  |          |
| Reverse Breakdown Voltage                     | $I_Z = 100 \mu A, T_J = 25^\circ C$        | 1.231       | 1.235 | 1.239 | 2.480       | 2.500 | 2.520 | V        |
|                                               | $0^\circ C \leq T_A \leq 70^\circ C$       | 1.225       | 1.235 | 1.245 | 2.470       | 2.500 | 2.530 | V        |
| Average Temperature Coefficient               | $I_{min} \leq I_Z \leq 20 \text{ mA}$      |             | 20    |       |             | 60    |       | ppm/°C   |
| Minimum Operating Current                     |                                            |             | 4     | 10    |             | 12    | 20    | $\mu A$  |
| Reverse Breakdown Voltage Change With Current | $I_{min} \leq I_Z \leq 1 \text{ mA}$       |             | 0.5   | 1     |             | 0.5   | 1     | mV       |
|                                               | Over Temperature                           |             | 0.5   | 1.5   |             | 0.5   | 1.5   | mV       |
|                                               | $1 \text{ mA} \leq I_Z \leq 20 \text{ mA}$ |             | 6.5   | 10    |             | 6.5   | 10    | mV       |
|                                               | Over Temperature                           |             | 6.5   | 20    |             | 6.5   | 20    | mV       |
| Reverse Dynamic Impedance                     | $I_Z = 100 \text{ mA}, f = 25 \text{ Hz}$  |             | 0.2   | 0.6   |             | 0.8   | 0.9   | $\Omega$ |
|                                               | Over Temperature                           |             | 1     | 1.5   |             |       | 1.5   | $\Omega$ |
| Wide Band Noise                               | $I_Z = 100 \mu A$                          |             |       |       |             |       |       |          |
|                                               | $10 \text{ Hz} \leq f \leq 10 \text{ KHz}$ |             | 60    |       |             | 60    |       | $\mu V$  |
| Long Term Stability                           | $I_Z = 100 \mu A$                          |             |       |       |             |       |       |          |
|                                               | $T_A = 25^\circ C \pm 0.1^\circ C$         |             | 20    |       |             | 60    |       | ppm/kH   |

## Typical Performance Curves

Calculating Average Temperature Coefficient for the AS1004-1.2V Reference

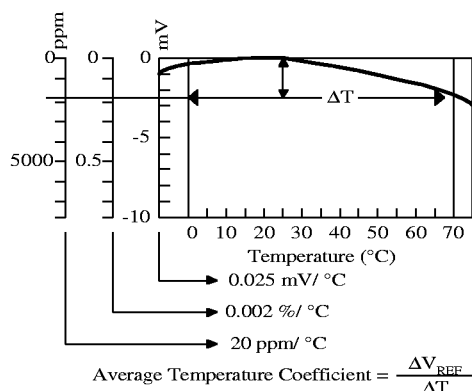


Figure 1

AS1004-1.2V Reference Voltage vs. Ambient Temperature

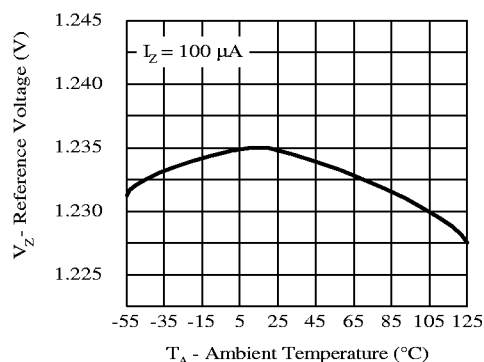
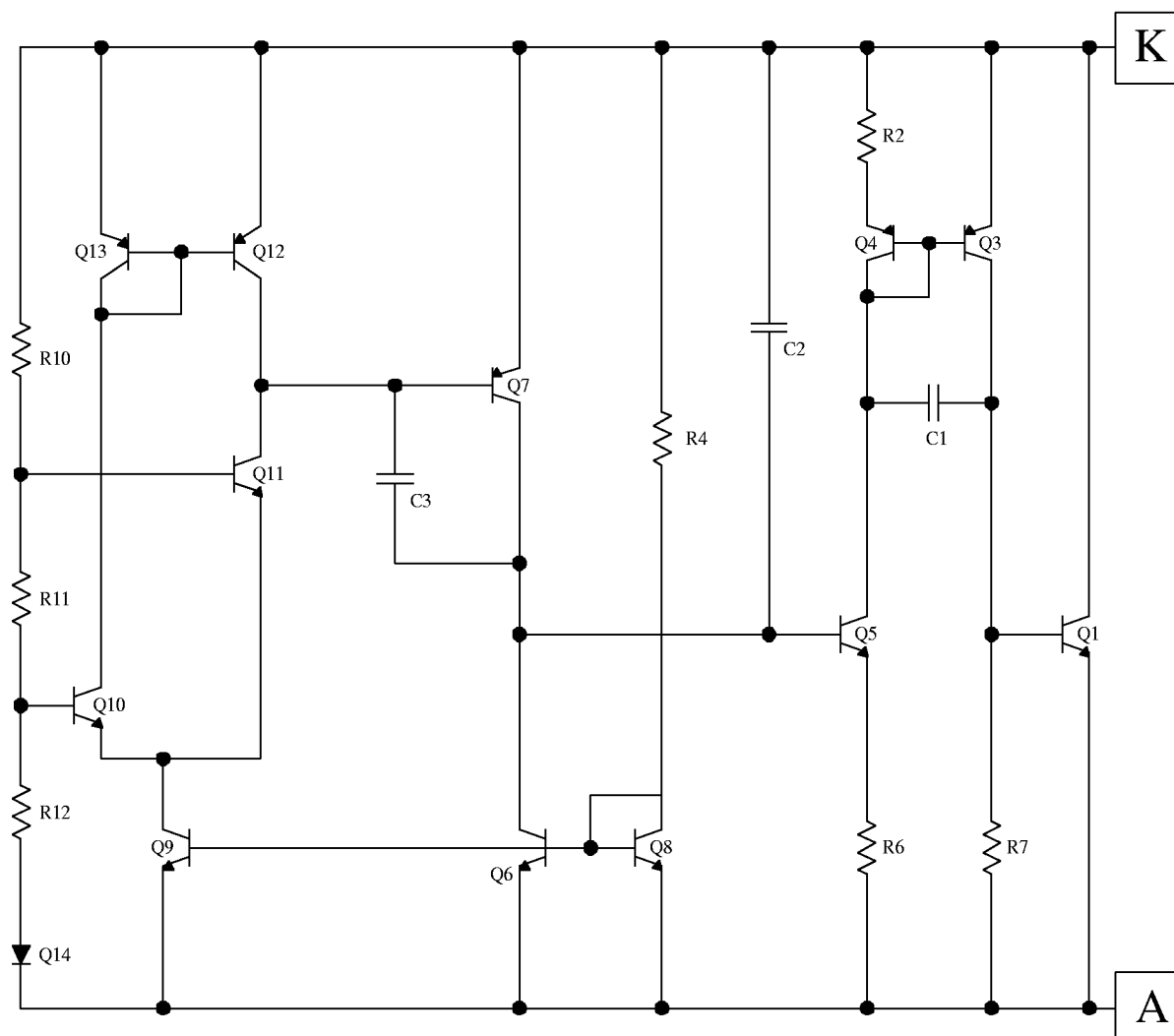


Figure 2

## SIMPLIFIED SCHEMATIC



## TYPICAL PERFORMANCE CURVES

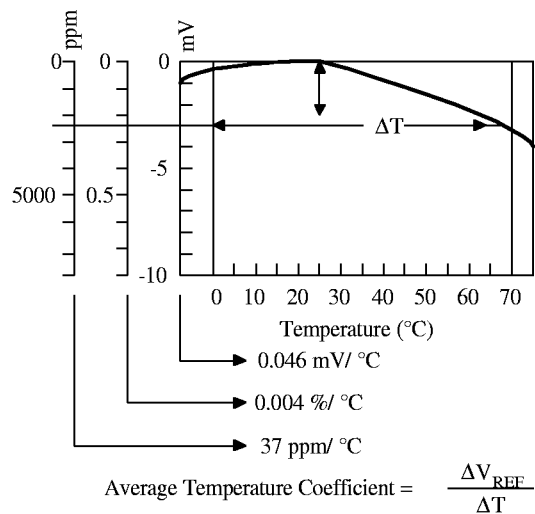
Calculating Average Temperature Coefficient  
for the AS1004-2.5V Reference

Figure 3

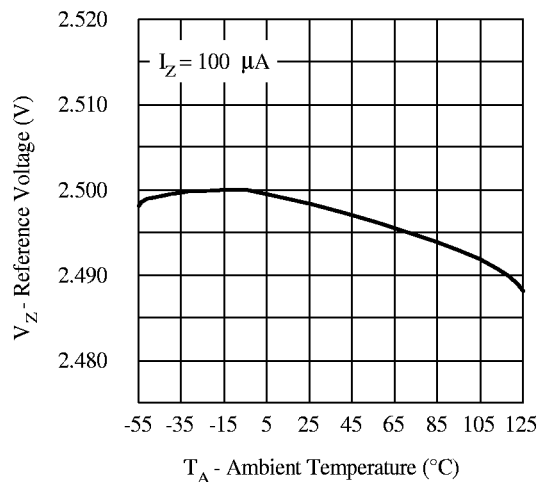
AS1004-2.5V Reference Voltage  
vs. Ambient Temperature

Figure 4

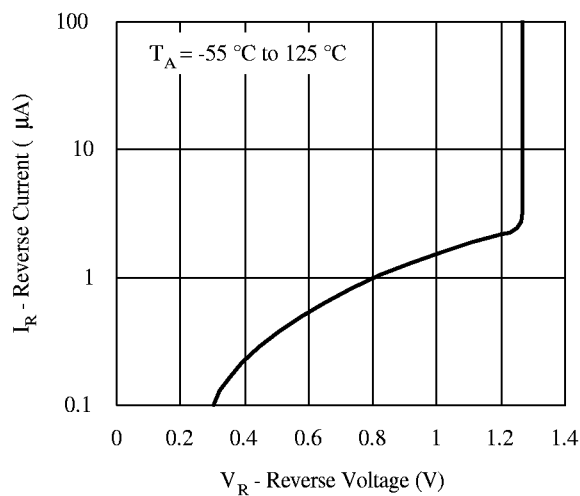
AS1004-1.2V Reverse Operating  
Characteristics

Figure 5

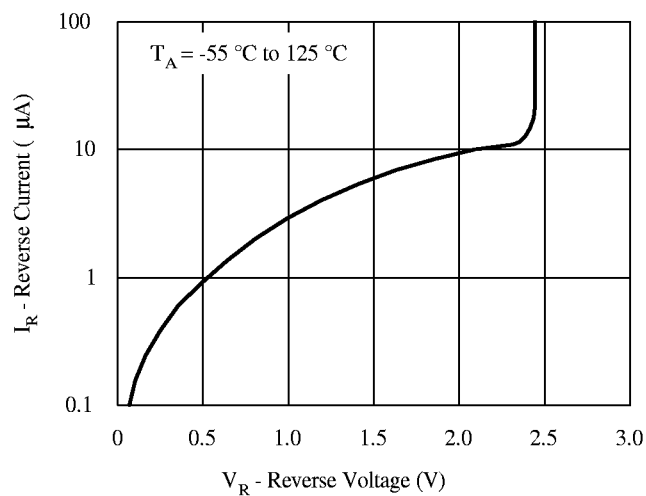
AS1004-2.5V Reverse Operating  
Characteristics

Figure 6

## TYPICAL PERFORMANCE CURVES

AS1004-1.2V Change in Reference Voltage vs. Reverse Current

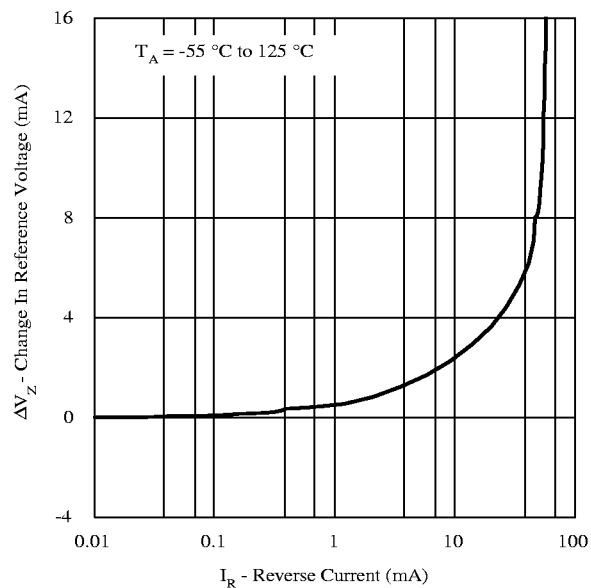


Figure 7

AS1004-2.5V Change in Reference Voltage vs. Reverse Current

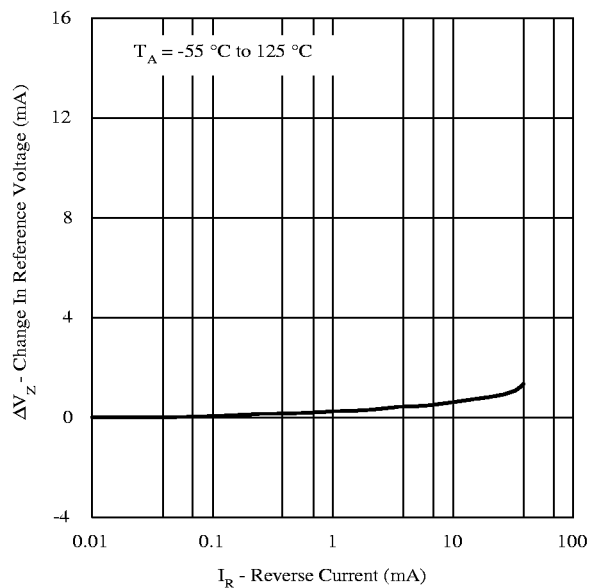


Figure 8

AS1004-1.2V Transient Response

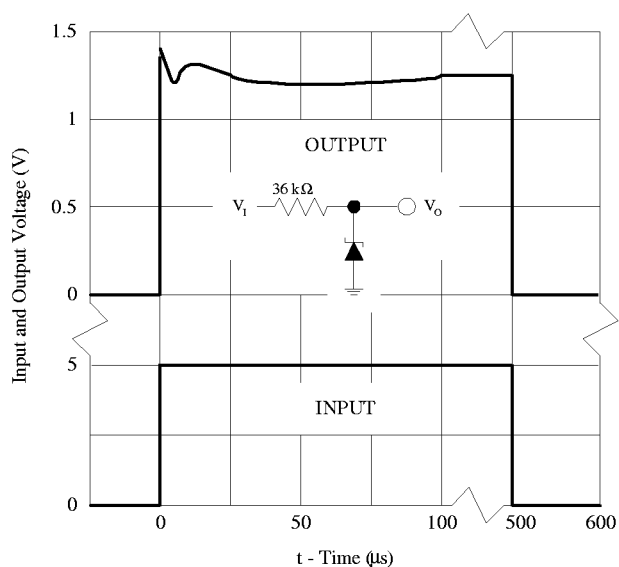


Figure 9

AS1004-2.5V Transient Response

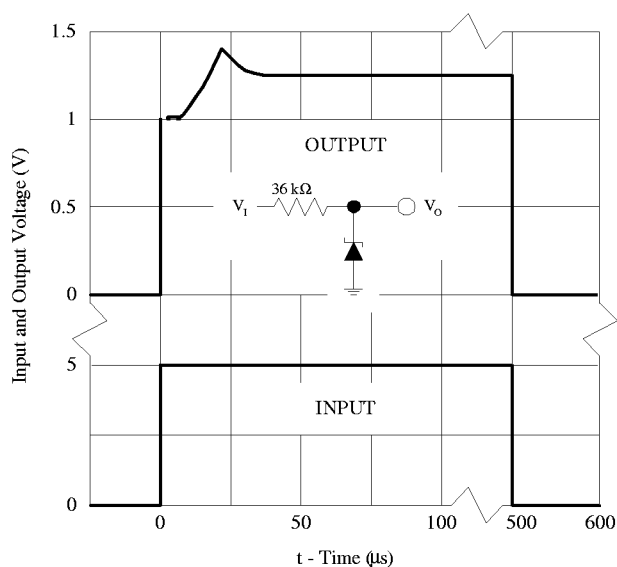


Figure 10

## TYPICAL PERFORMANCE CURVES

AS1004-1.2V Reverse Dynamic Impedance

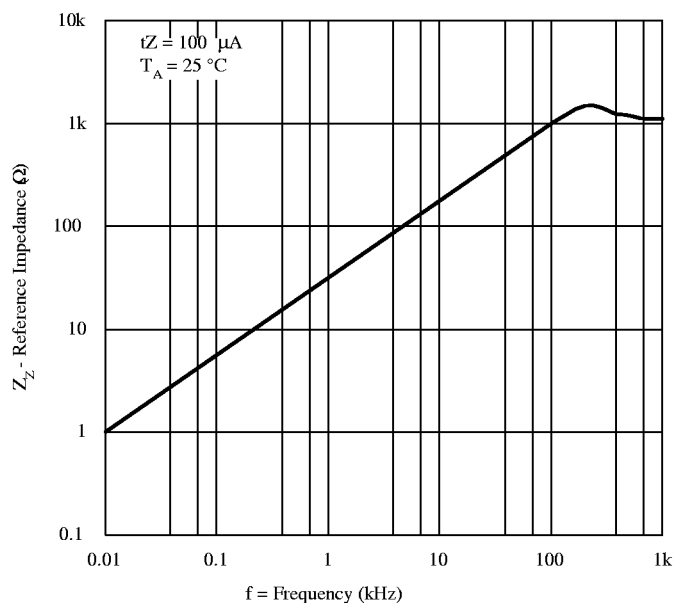


Figure 11

AS1004-2.5V Reverse Dynamic Impedance

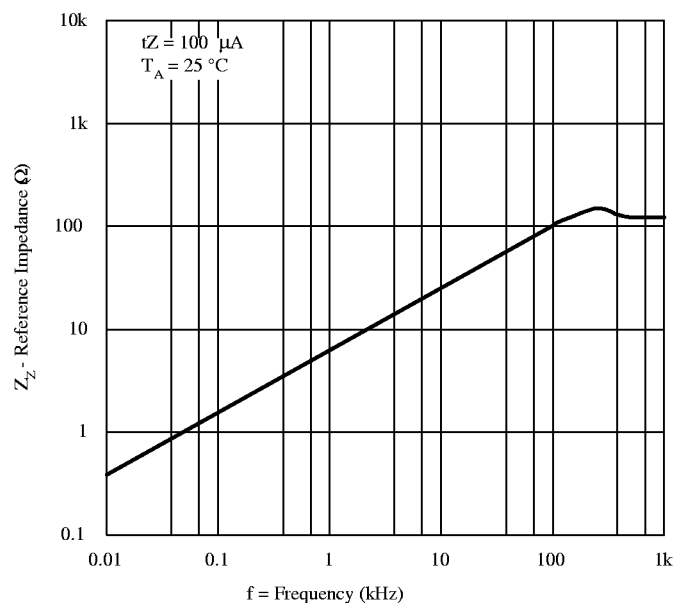


Figure 12

Forward Characteristics

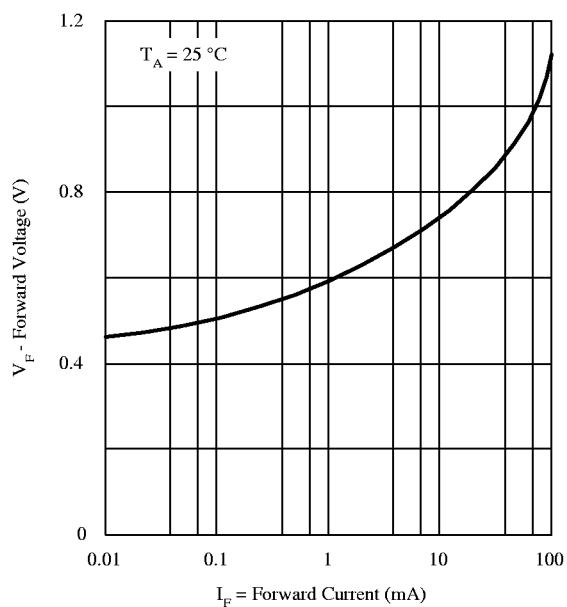


Figure 13

Low Frequency Reverse Dynamic Impedance

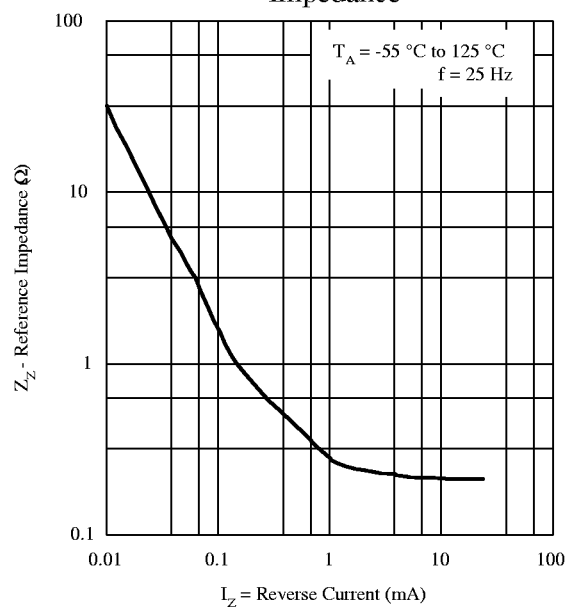


Figure 14

## TYPICAL APPLICATIONS

1.235 Reference

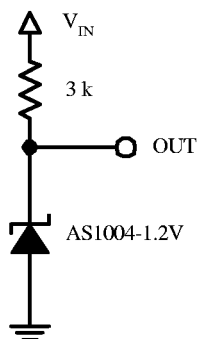


Figure 15

2.5V Reference

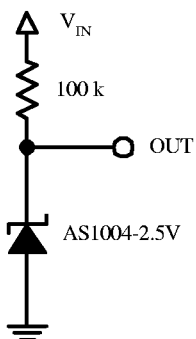


Figure 16

Low Noise Reference

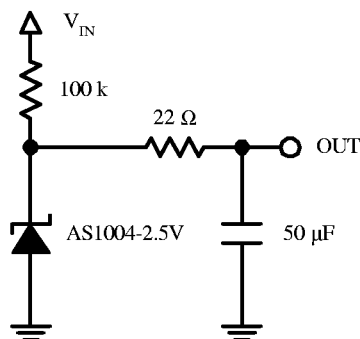


Figure 17

Variable Output Regulator

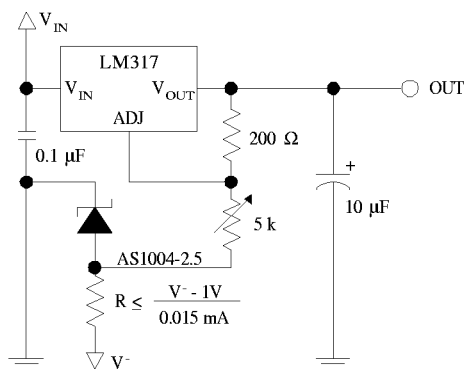


Figure 18

High Stability 5V Regulator

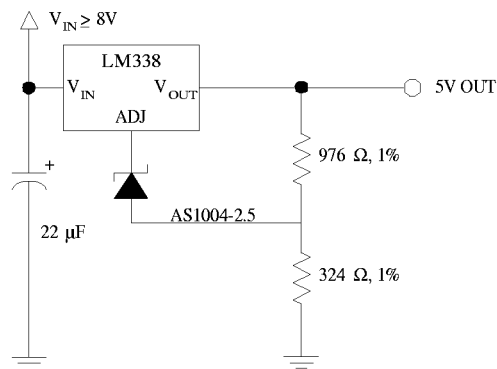


Figure 19

Lead Acid Low Battery Detector

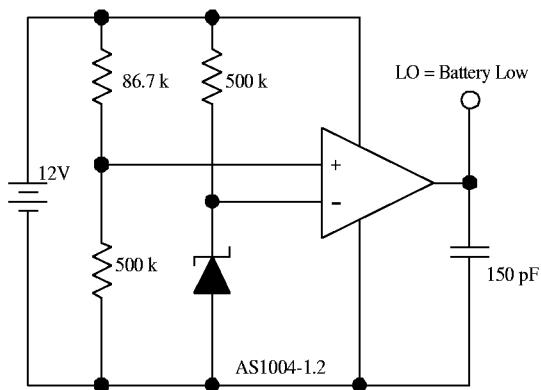


Figure 20

Micropower 10V Reference

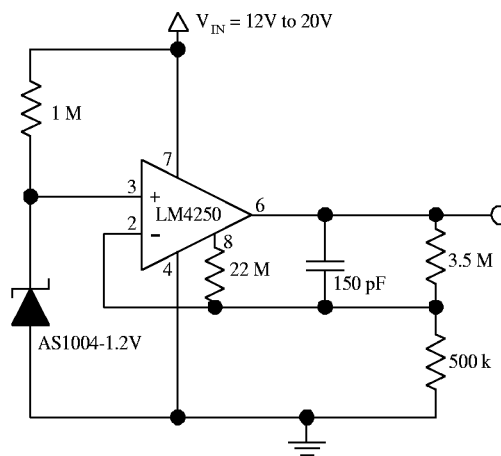


Figure 21